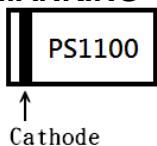


RoHS Compliant Product
A suffix of "-C" specifies halogen-free

FEATURES

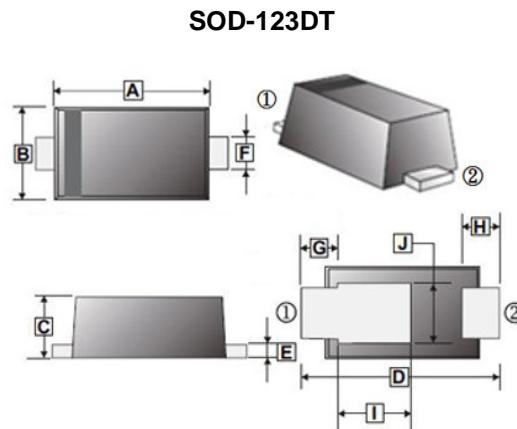
- Super Low V_F Schottky barrier diodes
- Low profile, typical thickness 0.8mm
- Low forward voltage drop
- Low leakage current
- Heatsink structure
- Moisture sensitivity: level 1, per J-STD-020
- High temperature soldering guaranteed: 260°C/10 seconds

MARKING



PACKAGE INFORMATION

Package	MPQ	Leader Size
SOD-123DT	3K	7 inch



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.90	3.10	F	0.85	1.05
B	1.90	2.10	G	0.60	REF.
C	0.75	0.90	H	0.40	0.85
D	3.50	3.90	I	1.66	REF.
E	0.10	0.25	J	1.30	1.70

ORDER INFORMATION

Part Number	Type
SM1100DT-C	Lead (Pb)-free and Halogen-free



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	
Maximum RMS Voltage	V_{RMS}	70	V
Maximum DC Blocking Voltage	V_{DC}	100	
Minimum Breakdown Voltage @ $I_R=1\text{mA}$	V_{BR}	100	
Maximum Average Forward Rectified Current	I_F	1	A
Peak Forward Surge Current, 8.3ms single half sine-wave Superimposed on rate load	I_{FSM}	30	A
Rating for Fusing ($t < 8.3\text{ms}$)	I^2t	3.8	A^2s
Maximum Instantaneous Forward Voltage @ $I_F=1\text{A}$	V_F	0.8	V
		0.65	
Maximum DC Reverse Current @ Rated DC Blocking Voltage	I_R	1	μA
		150	
Typical Junction Capacitance ³	C_J	28	pF
Typical Thermal Resistance, Junction-Ambient ¹	$R_{\theta JA}$	65	
Typical Thermal Resistance, Junction-Case ²	$R_{\theta JC}$	35	$^\circ\text{C/W}$
Typical Thermal Resistance, Junction-Lead ¹	$R_{\theta JL}$	9	
Operating Junction and Storage Temperature	T_J, T_{STG}	-55~150	$^\circ\text{C}$

Notes:

1. The thermal resistance from junction to ambient or lead, mounted on P.C.B with 5x5mm copper pads, 2oz, FR-4 PCB.
2. The thermal resistance from junction to case, mounted on P.C.B with recommended copper pads, 2oz, FR-4 PCB.
3. Measured at 1MHz and applied reverse voltage of 4V D.C.

CHARACTERISTIC CURVES

Figure 1. Forward Current Derating Curve

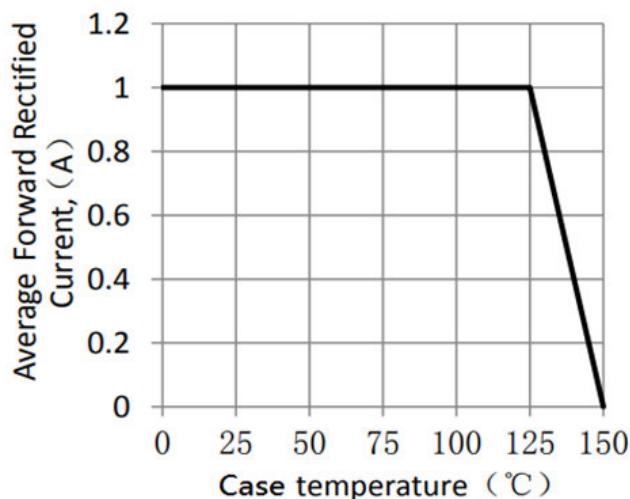


Figure 3. Typical Instantaneous Forward Characteristics

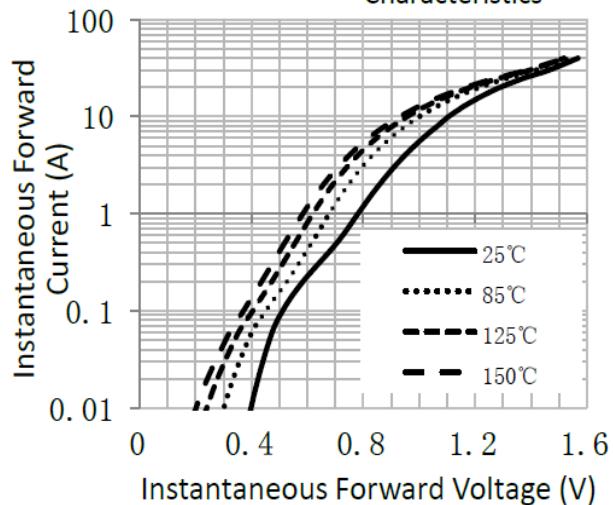


Figure 5. Typical Junction Capacitance

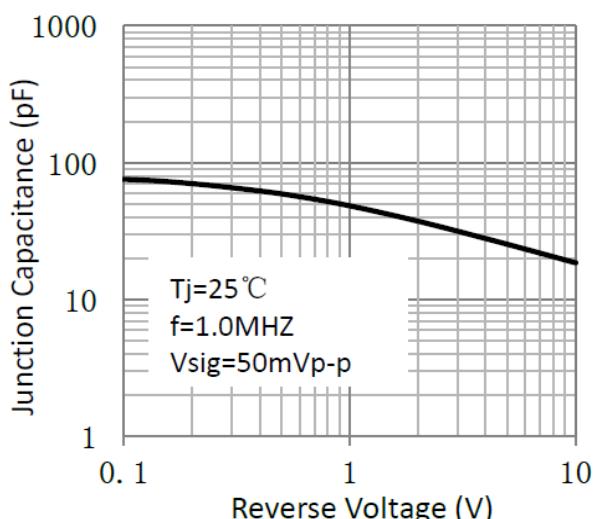


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

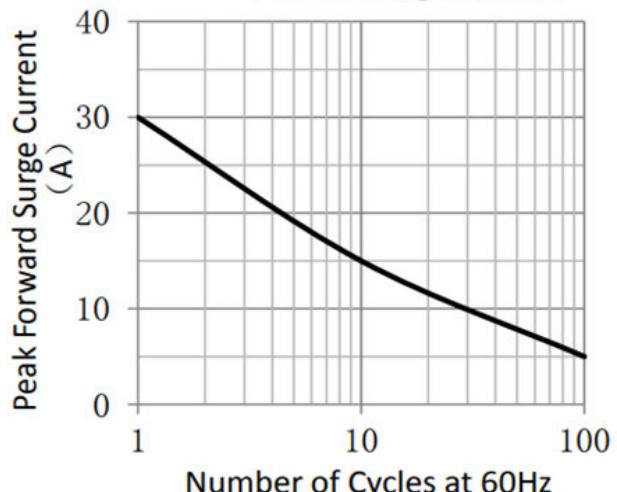


Figure 4. Typical Reverse Characteristics

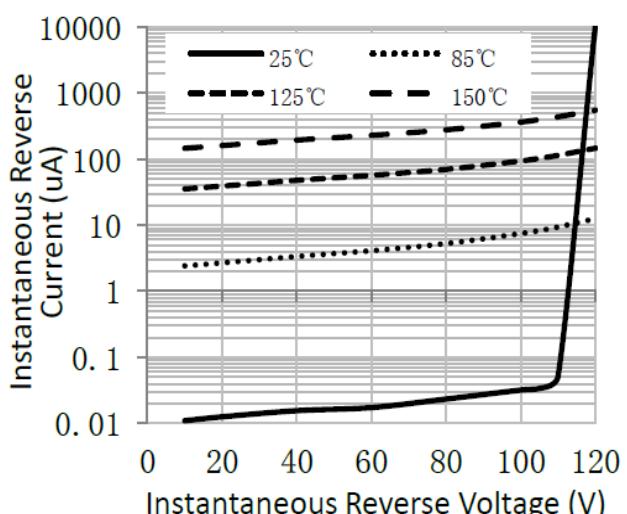
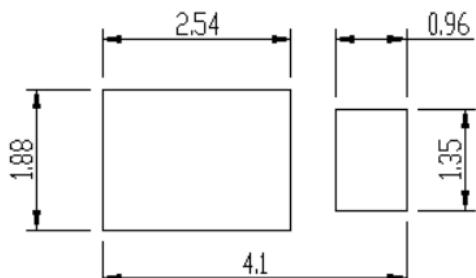


Figure 6. Mounting Pad Layout



*Dimensions in millimeters